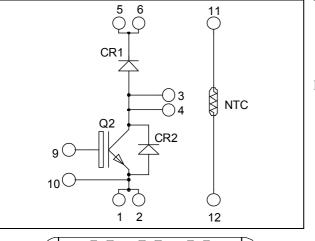
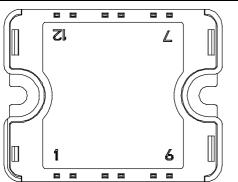


Boost chopper NPT IGBT Power Module

$I_{C} = 90A$ (*a*) $Tc = 80^{\circ}C$





Pins 1/2; 3/4; 5/6 must be shorted together

Absolute maximum ratings

Symbol Parameter Max ratings Unit Collector - Emitter Breakdown Voltage 600 V V_{CES} $T_c = 25^{\circ}C$ 110 I_C Continuous Collector Current $T_c = 80^{\circ}C$ 90 Α Pulsed Collector Current $T_c = 25^{\circ}C$ I_{CM} 315 V_{GE} Gate – Emitter Voltage ± 20 V $T_c = 25^{\circ}C$ P_{D} Maximum Power Dissipation 416 W $T_i = 150^{\circ}C$ RBSOA Reverse Bias Safe Operating Area 200A @ 600V

🕉 CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

$V_{CES} = 600V$

Application

- AC and DC motor control .
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Non Punch Through (NPT) Fast IGBT •
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- **RoHS** Compliant

1 - 7



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$ $T_i = 25^{\circ}C$				250	μA
		$V_{CE} = 600V$	$T_{i} = 125^{\circ}C$			500	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$ $T_j = 25^{\circ}C$			2.0	2.5	V
		$I_C = 90A$	$T_j = 125^{\circ}C$		2.2		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{mA}$		3		5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 V, V_{CE} = 0V$				±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			4300		
C _{oes}	Output Capacitance	$V_{CE} = 25V$		470		pF	
C _{res}	Reverse Transfer Capacitance	f = 1 MHz		400			
Qg	Total gate Charge	$V_{GE} = 15V$			330		
Q _{ge}	Gate – Emitter Charge	$V_{Bus} = 300V$			290		nC
Q _{gc}	Gate – Collector Charge	$I_C = 90A$			200		
T _{d(on)}	Turn-on Delay Time	Inductive Switch		26		ns	
Tr	Rise Time	$V_{GE} = 15V$		25			
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 400V$ $I_C = 90A$		150			
T _f	Fall Time	$R_G = 5 \Omega$			30		
T _{d(on)}	Turn-on Delay Time	Inductive Switch	ing (125°C)		26		
T _r	Rise Time	$V_{GE} = 15V$			25		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 90A$ $R_{G} = 5 \Omega$			170		ns
T _f	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125^{\circ}C$		4.3		
E _{off}	Turn-off Switching Energy	$I_{C} = 90A$ $R_{G} = 5 \Omega$	$T_j = 125^{\circ}C$		3.5		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I _{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25^{\circ}C$			100	μA
IRM			$T_{j} = 125^{\circ}C$			500	μΑ
I _F	DC Forward Current		$Tc = 80^{\circ}C$		100		Α
	Diode Forward Voltage	$I_F = 100A$			1.6	2	
V _F		$I_{\rm F} = 200 {\rm A}$		2		V	
		$I_{\rm F} = 100 {\rm A}$	$T_{j} = 125^{\circ}C$		1.3		
t	Reverse Recovery Time		$T_j = 25^{\circ}C$		160		ns
t _{rr}		$I_{\rm F} = 100 {\rm A}$ $V_{\rm R} = 400 {\rm V}$	$T_{j} = 125^{\circ}C$		220		115
Q _{rr}	Reverse Recovery Charge	$v_R = 400 v$ di/dt = 200 A/µs	$T_j = 25^{\circ}C$		290		nC
Qrr			$T_{j} = 125^{\circ}C$		1530		ne



Thermal and package characteristics

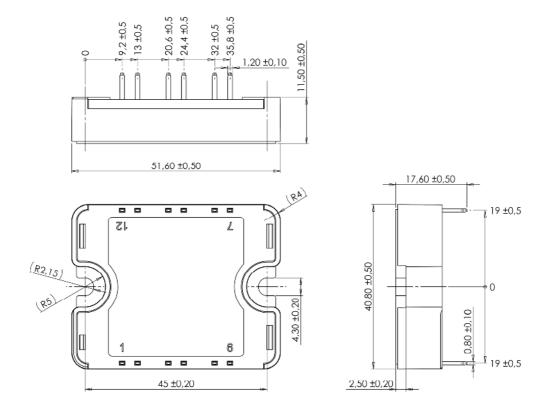
Symbol	Characteristic			Min	Тур	Max	Unit	
P	Lunction to Case Thermal Resistance		IGB	Т			0.3	°C/W
R _{thJC}			Diod	le			0.55	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V	
TJ	Operating junction temperature range			-40		150	Ĩ	
T _{STG}	Storage Temperature Range			-40		125	°C	
T _C	Operating Case Temperature						100	
Torque	Mounting torque	To heatsink		M4	2		3	N.m
Wt	Package Weight						80	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		Κ

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature
R_T: Thermistor value at T

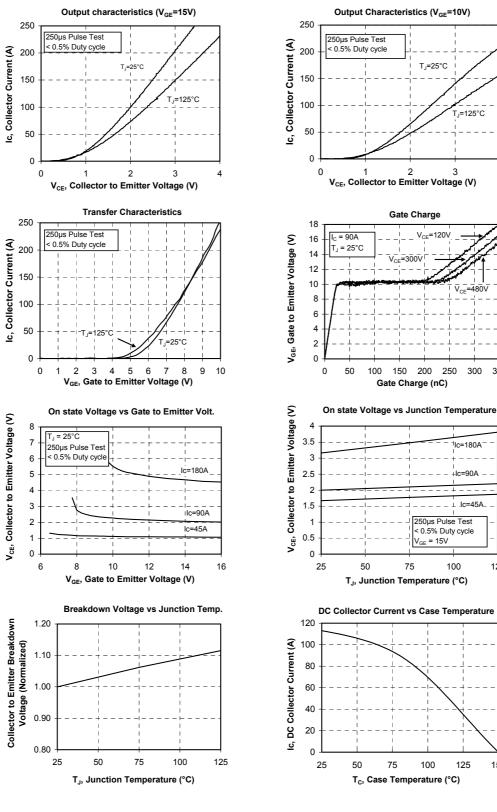
SP1 Package outline (dimensions in mm)



See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com



Typical Performance Curve



APTGF90DA60T1G

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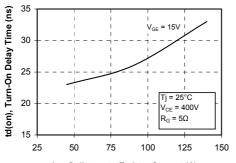
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125

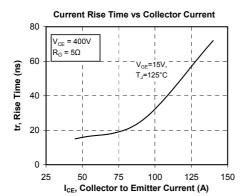
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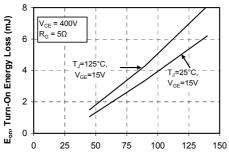
Turn-On Delay Time vs Collector Current

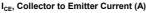


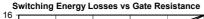
I_{CE}, Collector to Emitter Current (A)

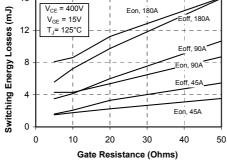




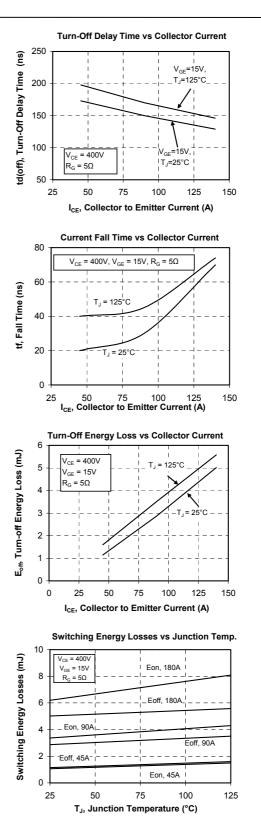




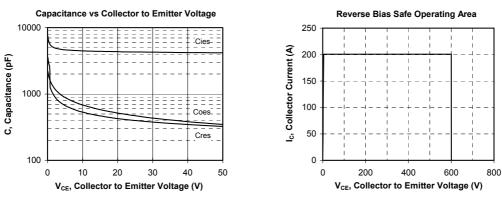


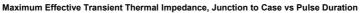


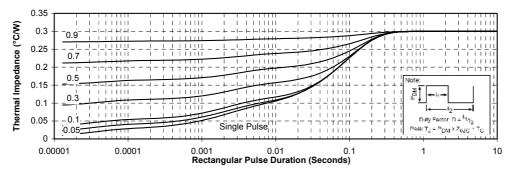
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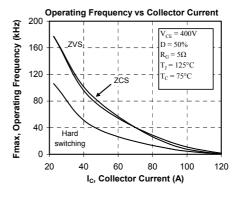














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